DATA SHEET

SKY67216-11: 500-1200 MHz Integrated Low-Noise Amplifier Module

Applications

- GSM, CDMA, WCDMA, LTE, and ISM systems
- Cellular infrastructure

Features

- Requires only one external component
- Optimized for 500 to 1200 MHz operation
- Noise Figure: 0.62 dB typical @ 850 MHz
- Gain: 19.1 dB typical @ 850 MHz
- Input return loss: 17 dB typical @ 850 MHz
- Output return loss: 18 dB typical @ 850 MHz
- Operating voltage range: 3.3 to 5.0 V
- Adjustable supply current: 30 to 120 mA
- High linearity IIP3: +16.4 dBm typical @ 850 MHz
- MCM (16-pin, 4 x 4 mm) package (MSL3, 260 °C per JEDEC J-STD-020) package

Skyworks Green™ products are compliant with all applicable legislation and are halogen-free. For additional information, refer to *Skyworks Definition of Green™*, document number SQ04-0074.

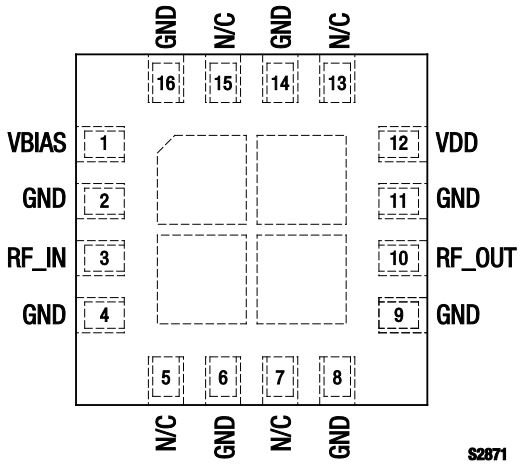


Figure 2. SKY67216-11 Pinout – 16-Pin MCM Package (Top View)

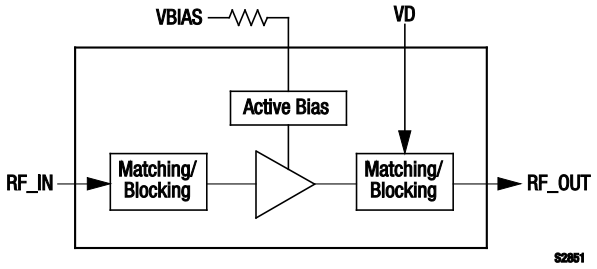


Figure 1. SKY67216-11 LNA Block Diagram

Description

The SKY67216-11 is a high performance, Low-Noise Amplifier (LNA) designed for use in 500 to 1200 MHz wireless infrastructure applications. The device consists of a single high linearity, LNA and all associated matching components. The only external component necessary for proper operation is an external resistor, used to set the DC current. The device is also completely DC bypassed.

The package design nearly eliminates external surface mount components, greatly reduces printed circuit board area, and offers low thermal resistance for enhanced Mean Time Between Failures (MTBFs).

For optimum performance in the following frequency ranges, refer to the following product Data Sheets (all devices are pin-to-pin compatible with the SKY67216-11):

- 400 MHz to 700 MHz: SKY67215-11 (document #201842)
- 1.6 GHz to 2.1 GHz: SKY67221-11 (document #201838)
- 2.2 GHz to 3.0 GHz: SKY67226-11 (document #201841)

The SKY67216-11 is packaged in a 16-pin, 4 x 4 mm Multi-Chip Module (MCM). A block diagram of the SKY67216-11 is shown in Figure 1.The device package and pinout are shown in Figure 2.

Electrical and Mechanical Specifications

Signal pin assignments and functional pin descriptions are described in Table 1. The absolute maximum ratings of the SKY67216-11 are provided in Table 2. Electrical specifications are provided in Table 3.

Typical performance characteristics of the SKY67216-11 are illustrated in Figures 3 through 23 (65 mA supply current).

Package and Handling Information

Since the device package is sensitive to moisture absorption, it is baked and vacuum packed before shipping. Instructions on the shipping container label regarding exposure to moisture after the container seal is broken must be followed. Otherwise, problems related to moisture absorption may occur when the part is subjected to high temperature during solder assembly.

The SKY67216-11 is rated to Moisture Sensitivity Level 3 (MSL3) at 260 °C. It can be used for lead or lead-free soldering. For additional information, refer to the Skyworks Application Note *PCB Design and SMT Assembly/Rework Guidelines for MCM-L Packages*, document number 101752.

Care must be taken when attaching this product, whether it is done manually or in a production solder reflow environment. Production quantities of this product are shipped in a standard tape and reel format.

Table 1. SKY67216-11 Signal Descriptions

Pin #	Name	Description	Pin #	Name	Description
1	VBIAS	Low current bias for amplifier. External resistor sets current consumption.	9	GND	Ground
2	GND	Ground	10	RF_OUT	RF output, AC coupled. No external components required.
3	RF_IN	RF input, AC coupled. No external components required.	11	GND	Ground
4	GND	Ground	12	VDD	High current amplifier bias connection. No external bypassing required.
5	N/C	No connection	13	N/C	No connection
6	GND	Ground	14	GND	Ground
7	N/C	No connection	15	N/C	No connection
8	GND	Ground	16	GND	Ground

Table 2. Absolute Maximum Ratings

Parameter	Symbol	Minimum	Maximum	Units
Supply voltage	V_{DD}		5.5	V
RF input power	P_{IN}		+20	dBm
Channel temperature	T_{CH}		150	°C
Operating temperature	T_A	–55	+100	°C
Storage temperature	T_{STG}	–65	+150	°C
Thermal resistance	Θ_{JC}		68.8	°C/W

Note: Exposure to maximum rating conditions for extended periods may reduce device reliability. There is no damage to device with only one parameter set at the limit and all other parameters set at or below their nominal value. Exceeding any of the limits listed here may result in permanent damage to the device.

***CAUTION**: Although this device is designed to be as robust as possible, Electrostatic Discharge (ESD) can damage this device. This device must be protected at all times from ESD. Static charges may easily produce potentials of several kilovolts on the human body or equipment, which can discharge without detection. Industry-standard ESD precautions should be used at all times. The SKY67216-11 ESD threshold level is 500 VDC using Human Body Model (HBM) testing (Class 1B), 50 VDC using Man-Machine (MM) model testing (Class A), and 1000 VDC using Charged Device Model (CDM) testing (Class IV).*

Table 3. SKY67216-11 Electrical Characteristics (Note 1) (Note 2) (Note 3)
(V_{DD} = VBIAS = 5 V Nominal, I_{DD} = 65 mA, T_A = +25 °C, Characteristic Impedance [Z_O] = 50 Ω, Unless Otherwise Noted)

Parameter	Symbol	Test Conditions	Minimum	Typical	Maximum	Units
RF Specifications						
Noise Figure (Note 4)	NF	@ 850 MHz		0.62	0.95	dB
Small signal gain	|S21|	@ 850 MHz	17.4	19.1		dB
Input return loss	|S11|	@ 850 MHz	13	18		dB
Output return loss	|S22|	@ 850 MHz	14	19		dB
Reverse isolation	|S12|	@ 850 MHz	26.7	28.7		dB
3rd Order Input Intercept Point	IIP3	@ 850 MHz, Δf = 1 MHz, P_{IN} = –20 dBm/tone	+13.4	+16.4		dBm
3rd Order Output Intercept Point	OIP3	@ 850 MHz, Δf = 1 MHz, P_{IN} = –20 dBm/tone	+32.5	+35.5		dBm
Input 1dB Compression Point	IP1dB	@ 850 MHz	+0.9	+2.9		dBm
Output 1dB Compression Point	OP1dB	@ 850 MHz	+19	+21		dBm
Stability (Note 3)	μ1, μ2, K, B	Up to 18 GHz, –40 °C to +85 °C		>1		–
DC Specifications						
Supply voltage	V_{DD}			5		V
Quiescent current	I_{DD}	R_{BIAS} = 9.1 kΩ		65		mA

Note 1: Performance is guaranteed only under the conditions listed in this Table.

Note 2: Circuit topology optimized for best compromise between NF, S11, IIP3, and IP1dB.

Note 3: Applies to typical application circuit and components shown in Figure 24.

Note 4: Loss from input SMA connector and Evaluation Board up to pin 3 of device has not been de-embedded from the NF measurement.

Table 4. SKY67216-11 Electrical Characteristics (Note 1) (Note 2) (Note 3)
(V_{DD} = VBIAS = 5 V Nominal, I_{DD} = 100 mA, T_A = +25 °C, Characteristic Impedance [Z_0] = 50 Ω, Unless Otherwise Noted)

Parameter	Symbol	Test Conditions	Minimum	Typical	Maximum	Units
RF Specifications						
Noise Figure (Note 4)	NF	@ 500 MHz @ 850 MHz @ 1200 MHz		0.70 0.62 0.85		dB dB dB
Small signal gain	|S21|	@ 500 MHz @ 850 MHz @ 1200 MHz		23.1 19.7 16.3		dB dB dB
Input return loss	|S11|	@ 500 MHz @ 850 MHz @ 1200 MHz		21.9 19.9 11.4		dB dB dB
Output return loss	|S22|	@ 500 MHz @ 850 MHz @ 1200 MHz		11.1 18.8 9.2		dB dB dB
Reverse isolation	|S12|	@ 500 MHz @ 850 MHz @ 1200 MHz		31.2 28.7 28.3		dB dB dB
3rd Order Input Intercept Point	IIP3	Δf = 1 MHz, P_{IN} = –20 dBm/tone: @ 500 MHz @ 850 MHz @ 1200 MHz		 +11.9 +19.9 +18.5		 dBm dBm dBm
3rd Order Output Intercept Point	OIP3	Δf = 1 MHz, P_{IN} = –20 dBm/tone: @ 500 MHz @ 850 MHz @ 1200 MHz		 +35.0 +39.6 +34.8		 dBm dBm dBm
Input 1dB Compression Point	IP1dB	@ 500 MHz @ 850 MHz @ 1200 MHz		–2.4 +2.9 +7.0		dBm dBm dBm
Output 1dB Compression Point	OP1dB	@ 500 MHz @ 850 MHz @ 1200 MHz		+19.7 +21.6 +22.3		dBm dBm dBm
Stability (Note 3)	μ1, μ2, K, B	Up to 18 GHz, –40 °C to +85 °C		>1		–
DC Specifications						
Supply voltage	V_{DD}			5		V
Quiescent current	I_{DD}	R_{BIAS} = 6.2 kΩ		100		mA

Note 1: Performance is guaranteed only under the conditions listed in this Table.

Note 2: Circuit topology optimized for best compromise between NF, S11, IIP3, and IP1dB.

Note 3: Applies to typical application circuit and components shown in Figure 24.

Note 4: Loss from input SMA connector and Evaluation Board up to pin 3 of device has not been de-embedded from the NF measurement.

Table 5. SKY67216-11 Electrical Characteristics (Note 1) (Note 2) (Note 3)
(V_{DD} = VBIAS = 5 V Nominal, I_{DD} = 45 mA, T_A = +25 °C, Characteristic Impedance [Z_0] = 50 Ω, Unless Otherwise Noted)

Parameter	Symbol	Test Conditions	Minimum	Typical	Maximum	Units
RF Specifications						
Noise Figure (Note 4)	NF	@ 500 MHz @ 850 MHz @ 1200 MHz		0.70 0.55 0.85		dB dB dB
Small signal gain	|S21|	@ 500 MHz @ 850 MHz @ 1200 MHz		22.70 19.15 15.80		dB dB dB
Input return loss	|S11|	@ 500 MHz @ 850 MHz @ 1200 MHz		16.4 17.7 11.9		dB dB dB
Output return loss	|S22|	@ 500 MHz @ 850 MHz @ 1200 MHz		10.8 20.9 9.7		dB dB dB
Reverse isolation	|S12|	@ 500 MHz @ 850 MHz @ 1200 MHz		31.2 29.0 28.7		dB dB dB
3rd Order Input Intercept Point	IIP3	Δf = 1 MHz, P_{IN} = –20 dBm/tone: @ 500 MHz @ 850 MHz @ 1200 MHz		 +6.80 +13.25 +14.50		 dBm dBm dBm
3rd Order Output Intercept Point	OIP3	Δf = 1 MHz, P_{IN} = –20 dBm/tone: @ 500 MHz @ 850 MHz @ 1200 MHz		 +29.5 +32.4 +30.3		 dBm dBm dBm
Input 1dB Compression Point	IP1dB	@ 500 MHz @ 850 MHz @ 1200 MHz		–2.4 +2.9 +6.7		dBm dBm dBm
Output 1dB Compression Point	OP1dB	@ 500 MHz @ 850 MHz @ 1200 MHz		+19.3 +21.1 +21.5		dBm dBm dBm
Stability (Note 3)	μ1, μ2, K, B	Up to 18 GHz, –40 °C to +85 °C		>1		–
DC Specifications						
Supply voltage	V_{DD}			5		V
Quiescent current	I_{DD}	R_{BIAS} = 12 kΩ		45		mA

Note 1: Performance is guaranteed only under the conditions listed in this Table.

Note 2: Circuit topology optimized for best compromise between NF, S11, IIP3, and IP1dB.

Note 3: Applies to typical application circuit and components shown in Figure 24.

Note 4: Loss from input SMA connector and Evaluation Board up to pin 3 of device has not been de-embedded from the NF measurement.

Typical Performance Characteristics @ I_{DD} = 65 mA

(V_{DD} = VBIAS = 5 V Nominal, T_A = +25 °C, Characteristic Impedance [Zo] = 50 Ω, Unless Otherwise Noted)

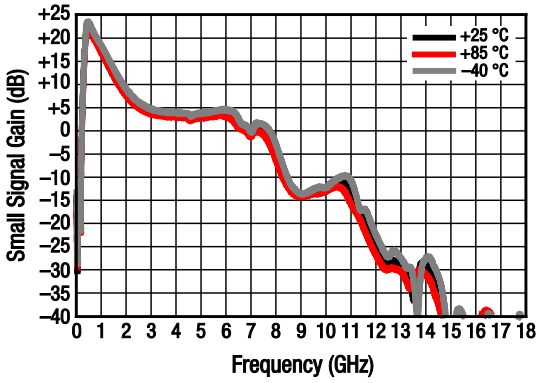


Figure 3. Broadband Gain Response vs Frequency Over Temperature

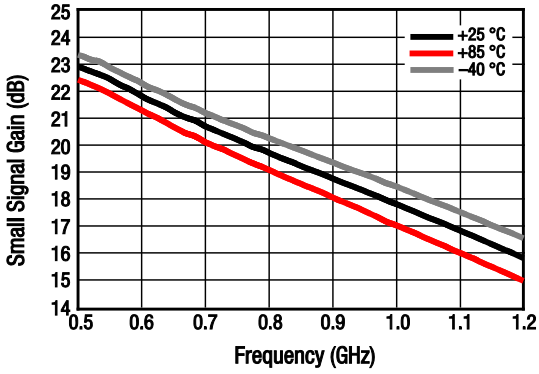


Figure 4. Narrowband Gain Response vs Frequency Over Temperature

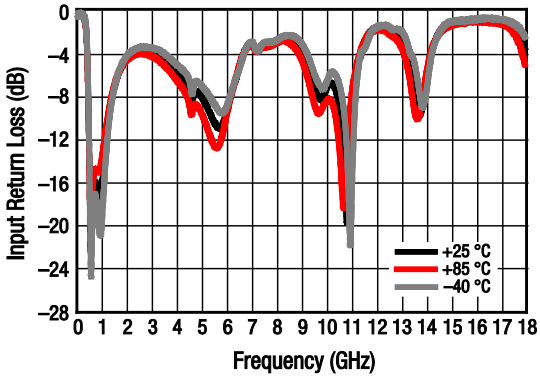


Figure 5. Broadband Input Return Loss vs Frequency Over Temperature

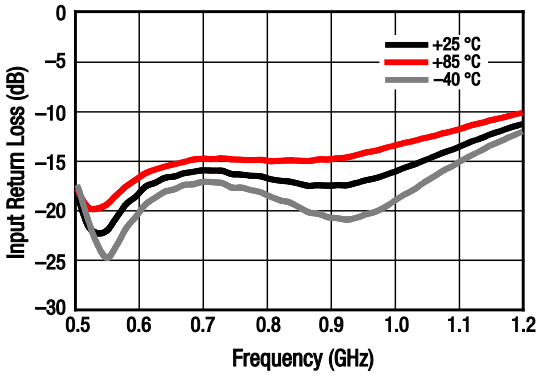


Figure 6. Narrowband Input Return Loss vs Frequency Over Temperature

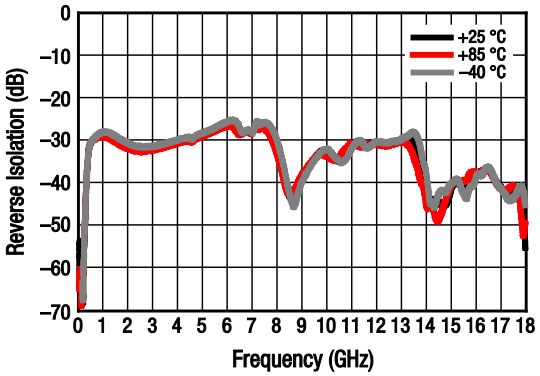


Figure 7. Broadband Reverse Isolation vs Frequency Over Temperature

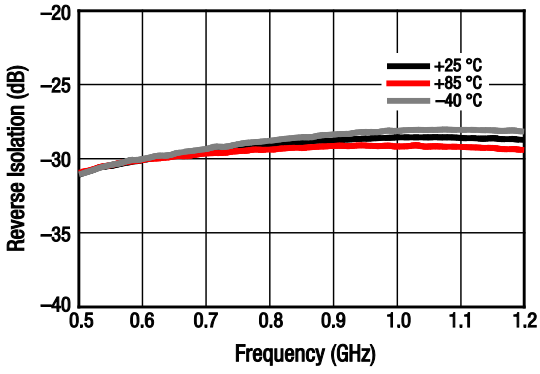


Figure 8. Narrowband Reverse Isolation vs Frequency Over Temperature

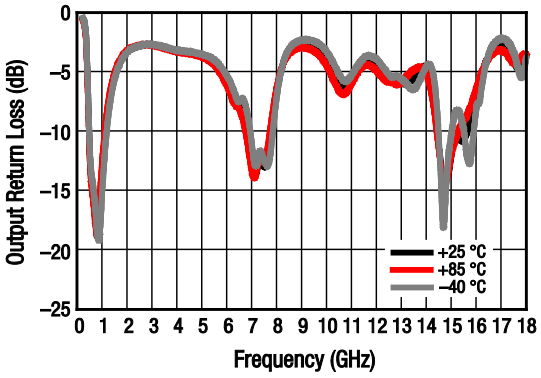


Figure 9. Broadband Output Return Loss vs Frequency Over Temperature

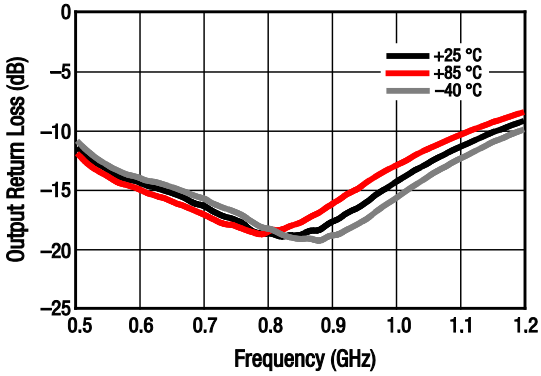


Figure 10. Narrowband Output Return Loss vs Frequency Over Temperature

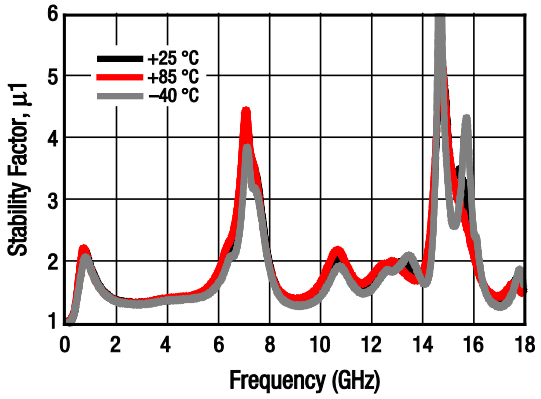


Figure 11. Stability Factor (µ1) vs Frequency Over Temperature

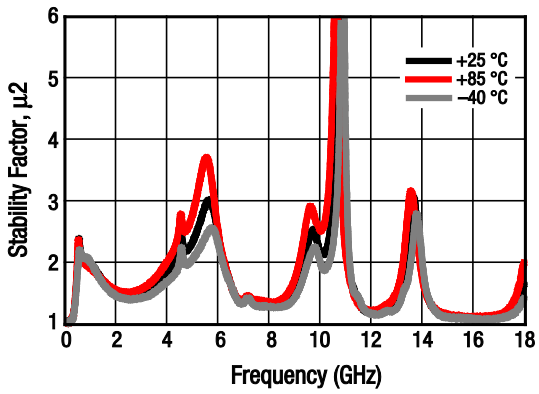


Figure 12. Stability Factor (µ2) vs Frequency Over Temperature

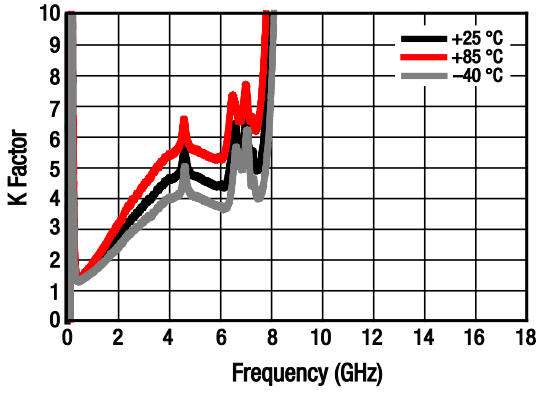


Figure 13. Stability Factor (K) vs Frequency Over Temperature

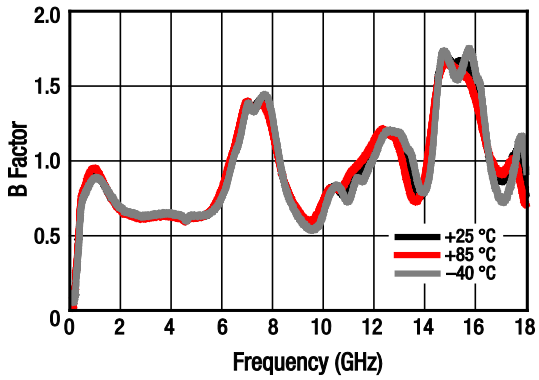


Figure 14. Stability Factor (B) vs Frequency Over Temperature

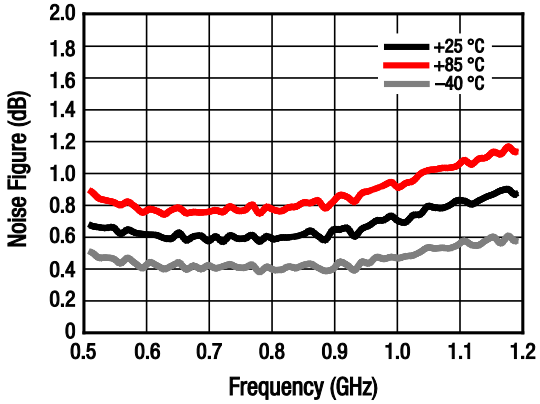


Figure 15. Noise Figure vs Frequency Over Temperature

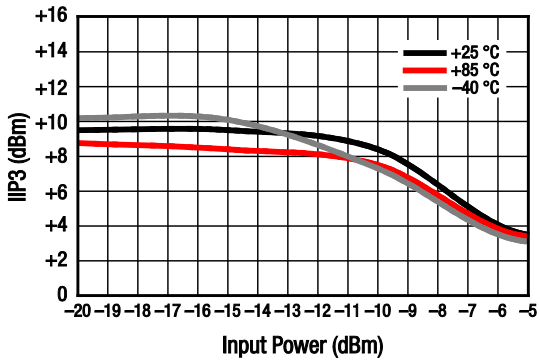


Figure 16. IIP3 vs Input Power Over Temperature @ 500 MHz (PIN = –20 dBm, Tone Spacing = 1 MHz)

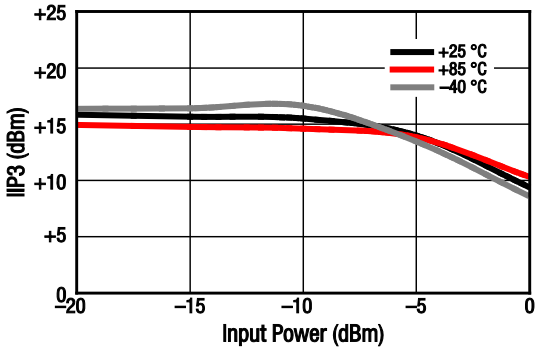


Figure 17. IIP3 vs Input Power Over Temperature @ 850 MHz (PIN = –20 dBm, Tone Spacing = 1 MHz)

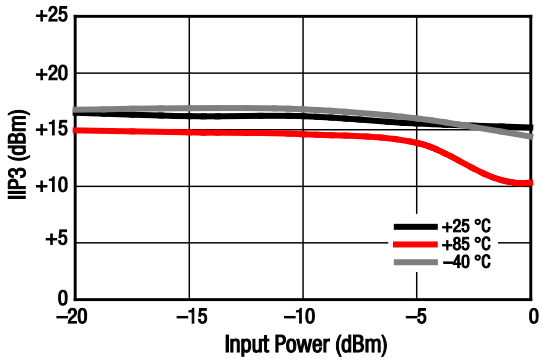


Figure 18. IIP3 vs Input Power Over Temperature @ 1200 MHz (PIN = –20 dBm, Tone Spacing = 1 MHz)

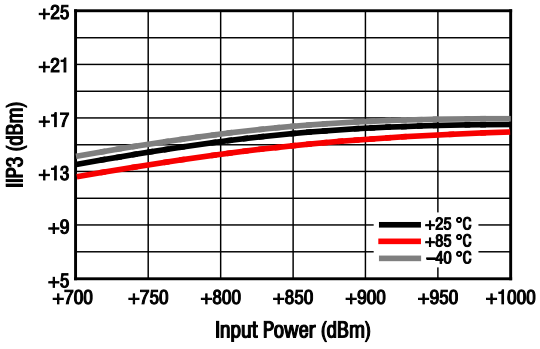


Figure 19. IIP3 vs Frequency Over Temperature (PIN = –20 dBm, Tone Spacing = 1 MHz)

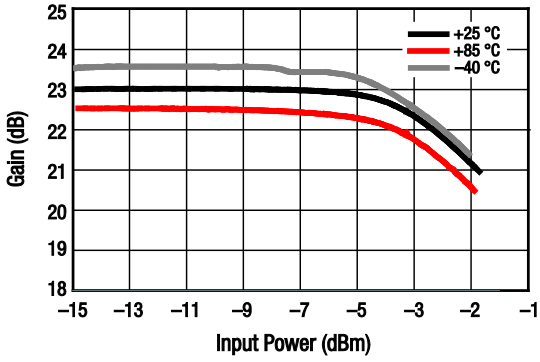


Figure 20. Gain vs Input Power Over Temperature @ 500 MHz

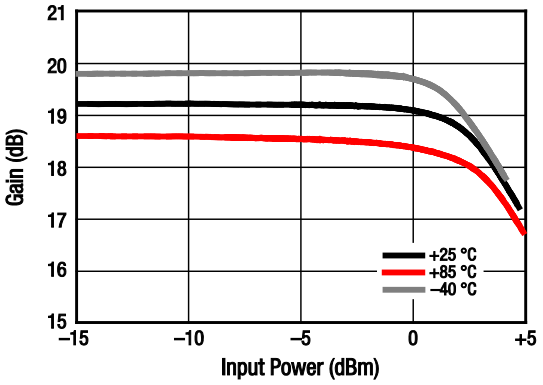


Figure 21. Gain vs Input Power Over Temperature @ 850 MHz

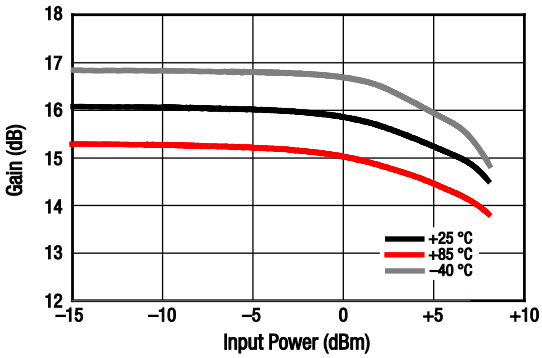


Figure 22. Gain vs Input Power Over Temperature @ 1200 MHz

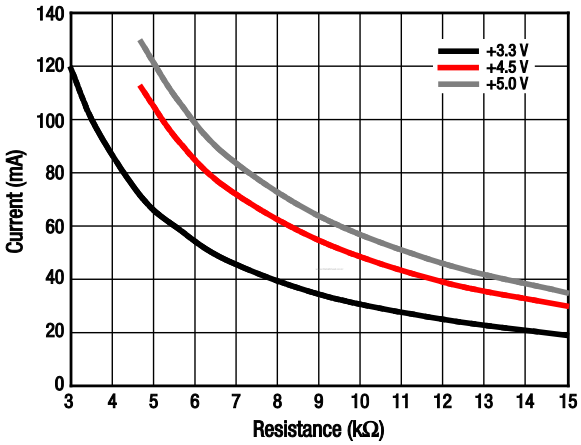


Figure 23. Resistor R1 vs Current Over Voltage

Evaluation Board Description

The SKY67216-11 Evaluation Board is used to test the performance of the SKY67216-11 LNA. The Evaluation Board schematic diagram is shown in Figure 24. An assembly drawing for the Evaluation Board is shown in Figure 25. The layer detail physical characteristics are noted in Figure 26. Table 7 provides the Bill of Materials (BOM) list for Evaluation Board components.

Package Dimensions

The PCB layout footprint for the SKY67216-11 is shown in Figure 27. Typical case markings are shown in Figure 28. Package dimensions for the 16-pin MCM are shown in Figure 29, and tape and reel dimensions are provided in Figure 30.

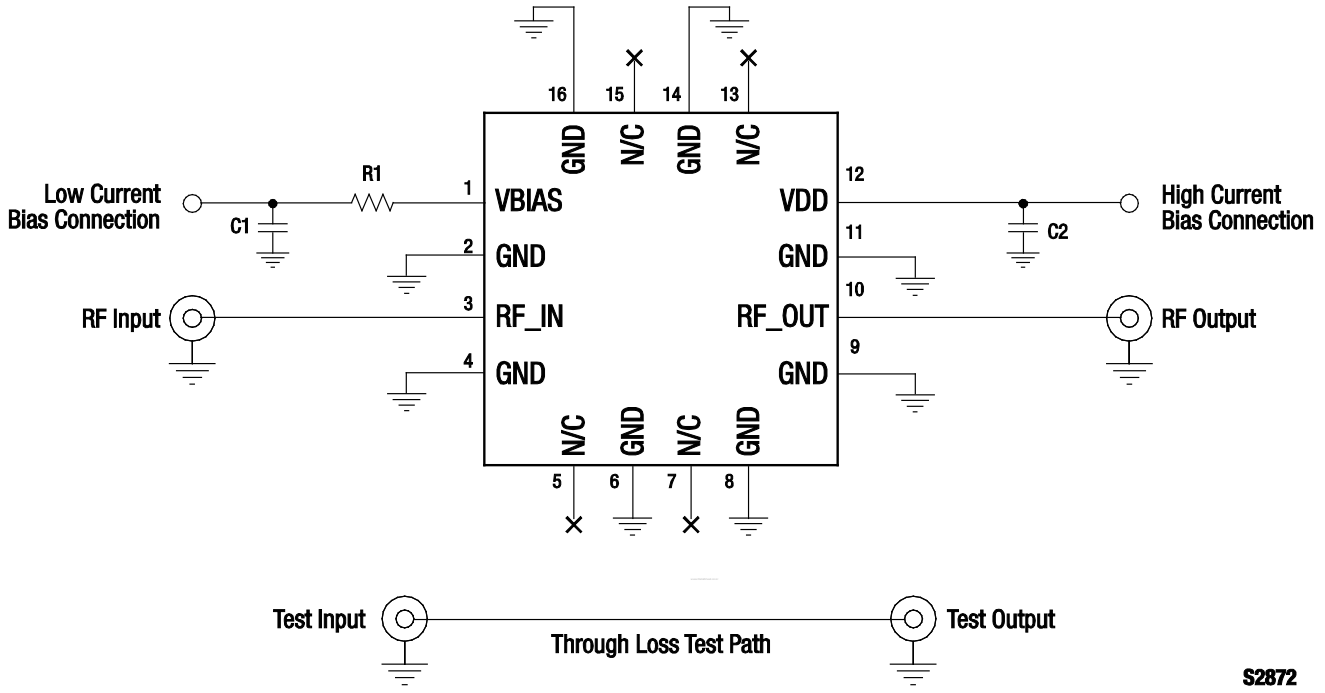


Figure 24. SKY67216-11 Schematic Diagram

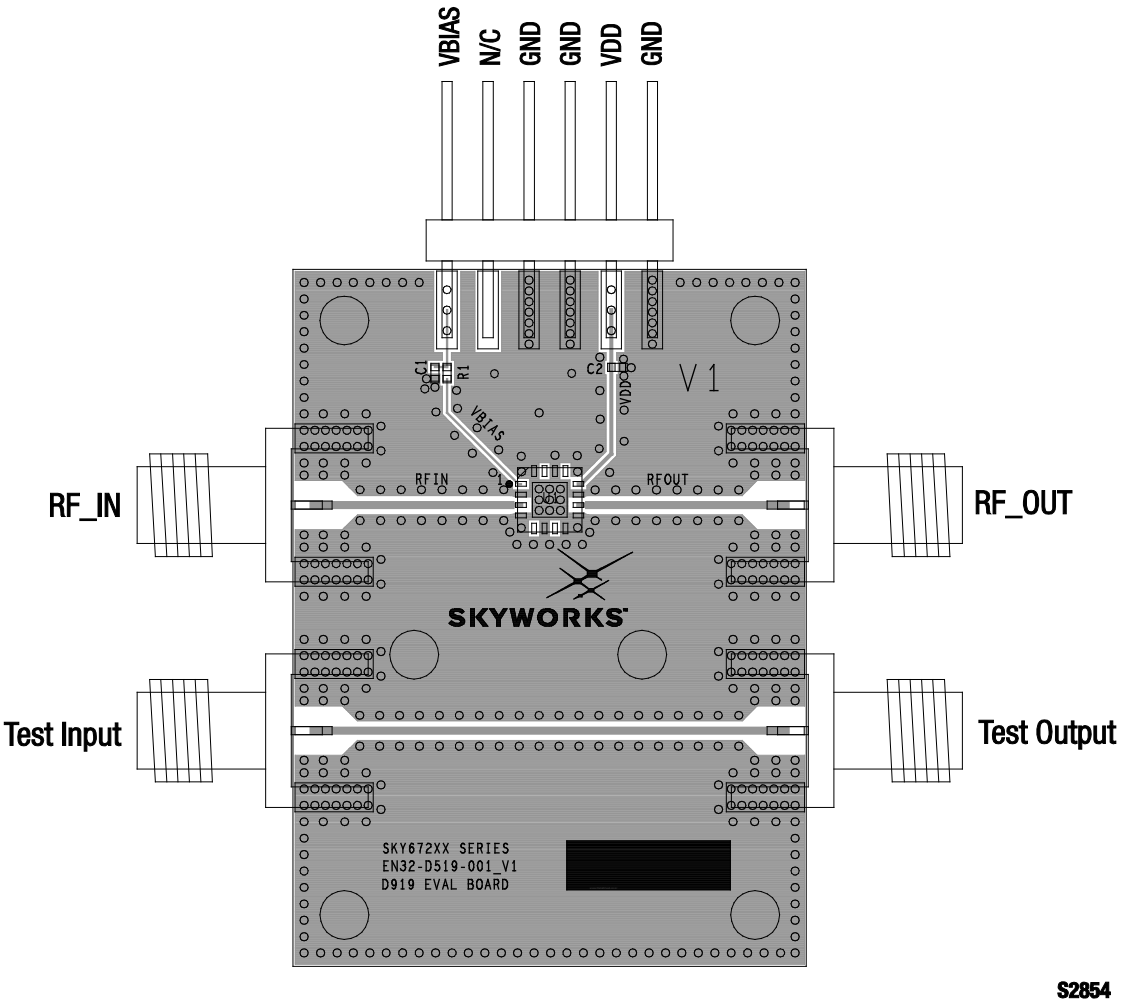


Figure 25. SKY67216-11 Evaluation Board Assembly Drawing

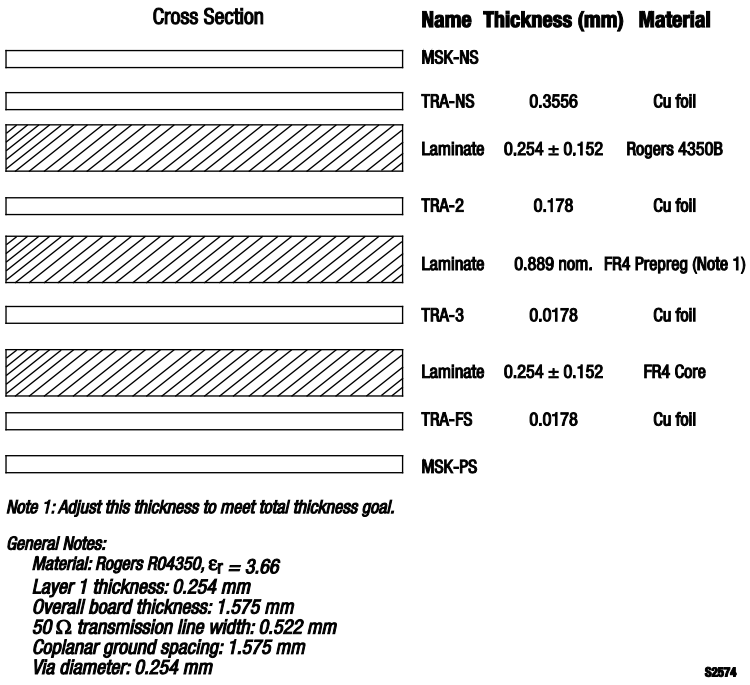


Figure 26. Layer Detail Physical Characteristics

Table 7. SKY67216-11 Evaluation Board (65 mA) Bill of Materials

Component	Size	Value	Vendor	Part Number
C1		DNI		
C2		DNI		
R1 for 65 mA operation (Note 1)	0402	9100 Ω	Panasonic	

Note 1: Placement in relation to component package is not critical.

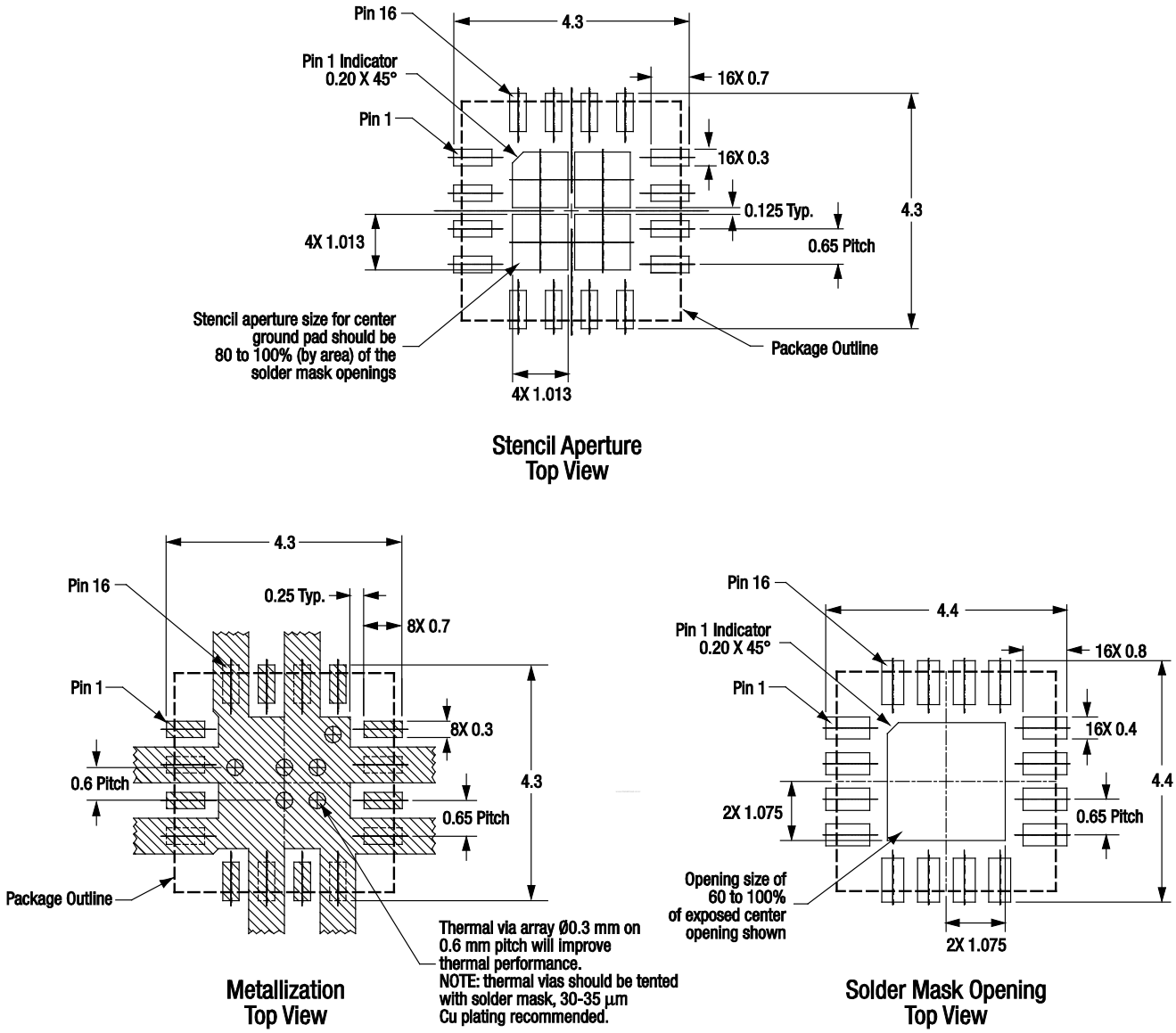


Figure 27. SKY67216-11 PCB Layout Footprint

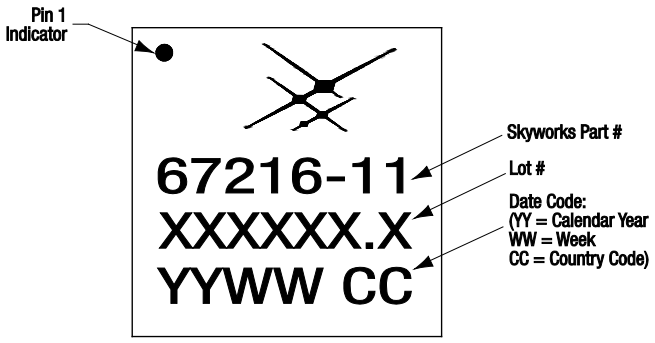


Figure 28. Typical Part Markings (Top View)

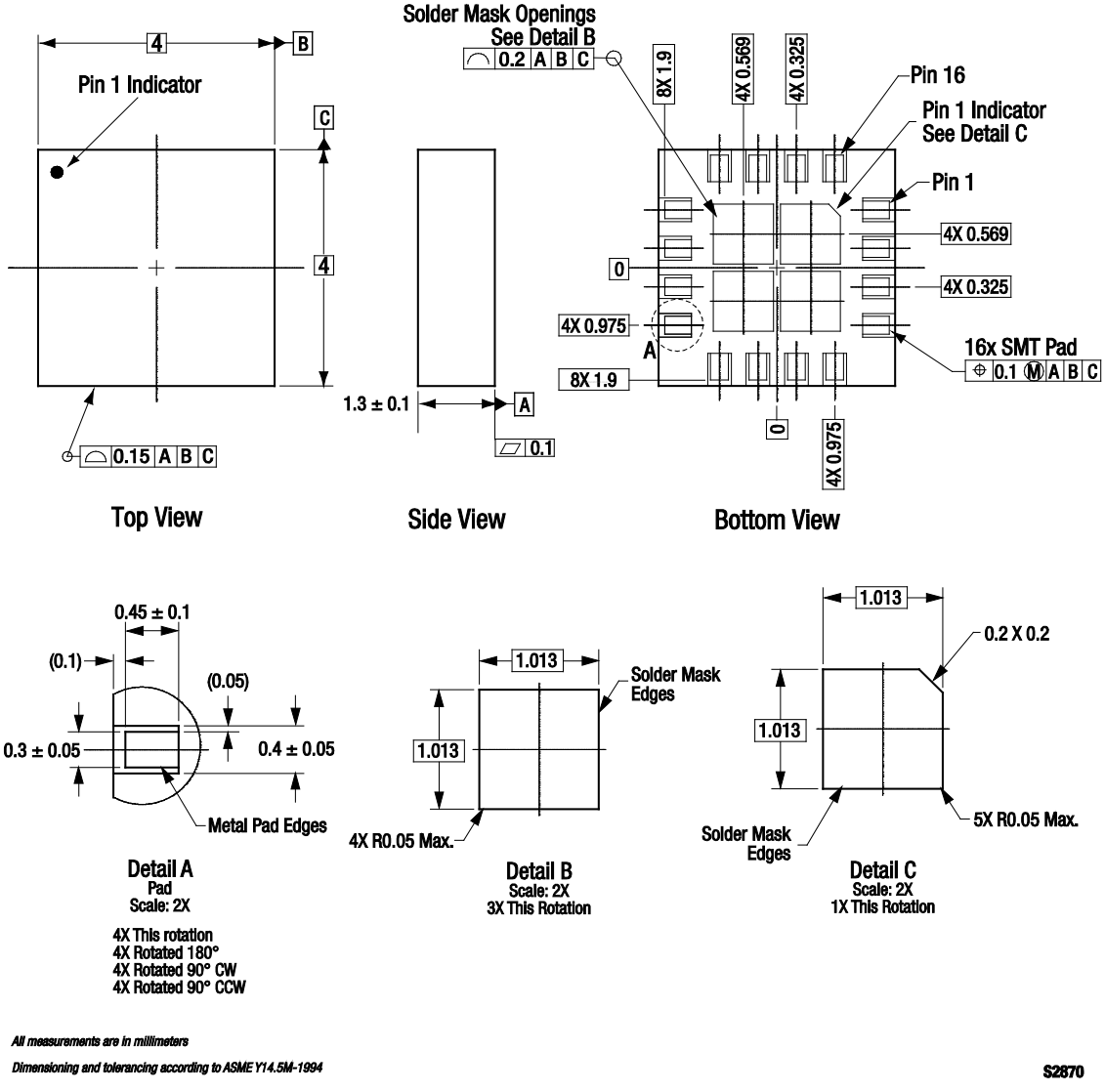
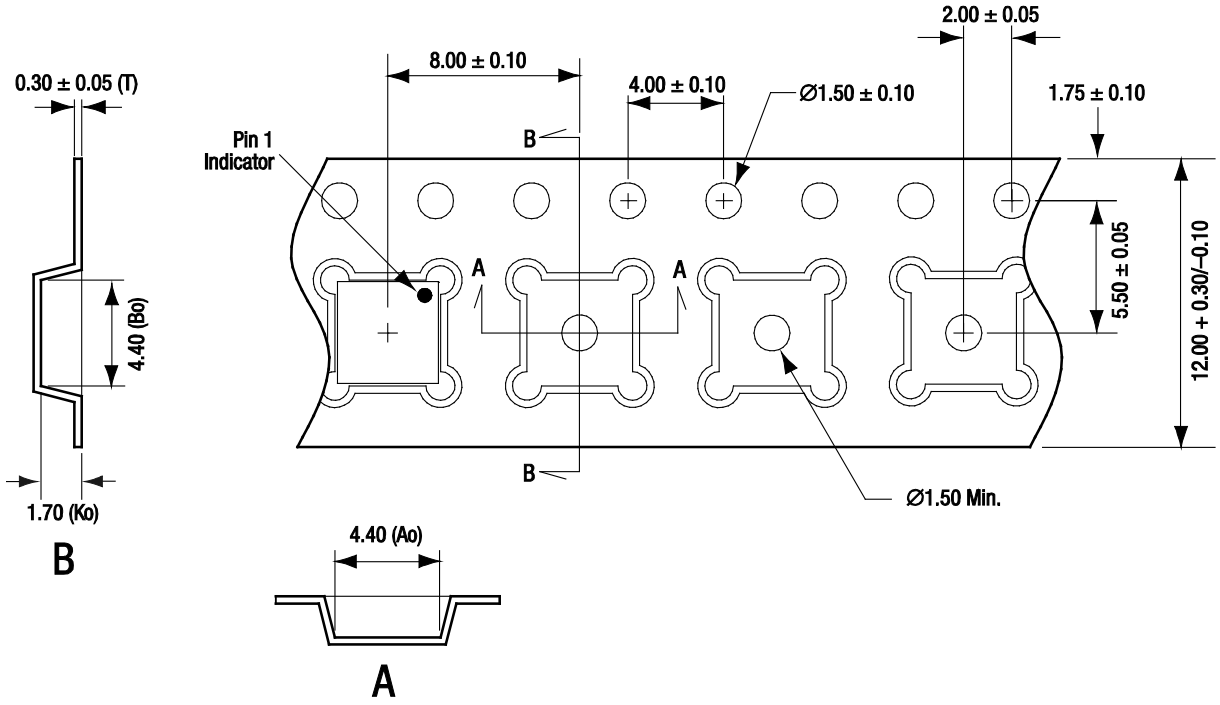


Figure 29. SKY67216-11 16-Pin MCM Package Dimensions



Notes:
1. *Carrier tape material: black conductive polycarbonate or polystyrene.*
2. *Cover tape material: transparent conductive PSA.*
3. *Cover tape size: 9.3 mm width.*
4. *Ten sprocket hole pitch cumulative tolerance: ±0.20 mm.*
5. *Ao and Bo measured on plane 0.30 mm above the bottom of the pocket.*
6. *Typical ESD surface resistivity is ≤1 x 10^{10} Ohms/square per EIA, JEDEC tape and reel specification.*
7. *All measurements are in millimeters*

S2031

Figure 30. SKY67216-11 Tape and Reel Dimensions

Ordering Information

Model Name	Manufacturing Part Number	Evaluation Board Part Number
SKY67216-11 500-1200 MHz LNA	SKY67216-11	EN32-D519-001_V1